# Code No: 132AA JAWAHARLAL NEHRU TECHNOLOGICAL UNIVERSITY HYDERABAD **B.Tech I Year II Semester Examinations, May - 2019 ENGINEERING PHYSICS – II** (Common to EEE, ECE, CSE, EIE, IT, ETM)

#### **Time: 3 hours**

### Max. Marks: 75

**Note:** This question paper contains two parts A and B. Part A is compulsory which carries 25 marks. Answer all questions in Part A. Part B consists of 5 Units. Answer any one full question from each unit. Each question carries 10 marks and may have a, b, c as sub questions.

# PART-A

|      |   | (25 Marks) |
|------|---|------------|
| 1.a) | Explain dual nature of light.                         | [2]        |
| b)   | Define de-Broglie's hypothesis.                       | [3]        |
| c)   | Define Fermi energy level at 0K.                      | [2]        |
| d)   | Draw V-I Characteristic curve of PN junction diode.   | [3]        |
| e)   | Define Polarization vector.                           | [2]        |
| f)   | Explain pyro electricity.                             | [3]        |
| g)   | Define magnetic susceptibility.                       | [2]        |
| h)   | Distinguish between soft and hard magnetic materials. | [3]        |
| i)   | What is nano size? Explain briefly.                   | [2]        |
| j)   | Write any two applications of nanomaterials.          | [3]        |

### **PART-B**

# (50 Marks)

| 2.a)<br>b) | With neat diagram explain Davisson and Germer's experiment.<br>Describe formation of energy bands in solids. | [5+5]     |
|------------|--|-----------|
| 2          |  |           |
| 3.a)       | Derive Schrödinger's time independent wave equation.   |           |
| b)         | Explain physical significance of wave function $(\psi)$ .  | [5+5]     |
| 4.a)       | Distinguish between direct and indirect band gap semiconductors.   |           |
| b)         | Determine the concentration of the charge carriers in conduction band of                                     | intrinsic |
| - /        | semiconductors.  | [4+6]     |
|            | OR   |           |
| 5.a)       | Explain formation of PN junction diode.  |           |
| b)         | Describe construction and working principle of Solar Cell.   | [4+6]     |
| 6.a)       | Derive an expression for Clausius-Mosotti relation.  |           |
| b)         | Describe Ferro electricity of a dielectric material  | [5+5]     |
| 0)         | OR   | [0   0]   |
| 7.a)       | Derive an expression for electronic polarizability.  |           |
| b)         | Discuss Piezo electricity of a dielectric material   | [5+5]     |
| 0)         |  | [3+3]     |

# www.manaresults.co.in

**R16** 

| 8.a)  | Discuss classification of magnetic materials.                             |       |
|-------|---|-------|
| b)    | Explain hysteresis curve based on domain theory of ferro magnetism.       | [5+5] |
|       | OR  |       |
| 9.a)  | What is Meissner's effect? Write any two applications of superconductors. |       |
| b)    | Derive an expression for Bohr magneton.                                   | [5+5] |
| 10.a) | Explain how surface to volume ratio varies in nano materials.             |       |
| b)    | Describe preparation of nanomaterials by using Sol-Gel method.            | [4+6] |
|       | OR  |       |
| 11.a) | Explain Quantum confinement.  |       |
| b)    | Explain how the nanomaterials are characterized by using SEM and TEM.     | [4+6] |
|       |   |       |

---00000----

www.manaresults.co.in